

Supporting Information for  
**In-intercalation and Si-containing protective layer enhance  
electrochemical performance of  $\text{NaNi}_{0.5}\text{Mn}_{0.5}\text{O}_2$  for sodium-ion  
batteries**

Peng Sun,<sup>a</sup> Chenhui Wang,<sup>a</sup> Jing Liu,<sup>a</sup> Jie Liao,<sup>a</sup> Yaohan Fei,<sup>a</sup> Ziyan Zhang,<sup>a</sup> Ning Nie,<sup>b</sup> Jiangjiexing Wu,<sup>c,\*</sup> You Han,<sup>a</sup> Jinli Zhang<sup>a</sup> and Wei Li<sup>a,\*</sup>

<sup>a</sup> School of Chemical Engineering and Technology, Tianjin University, Tianjin, 300350, P. R. China.

<sup>b</sup> Viterbi School of Engineering, University of Southern California, Los Angeles, California, 90089, USA.

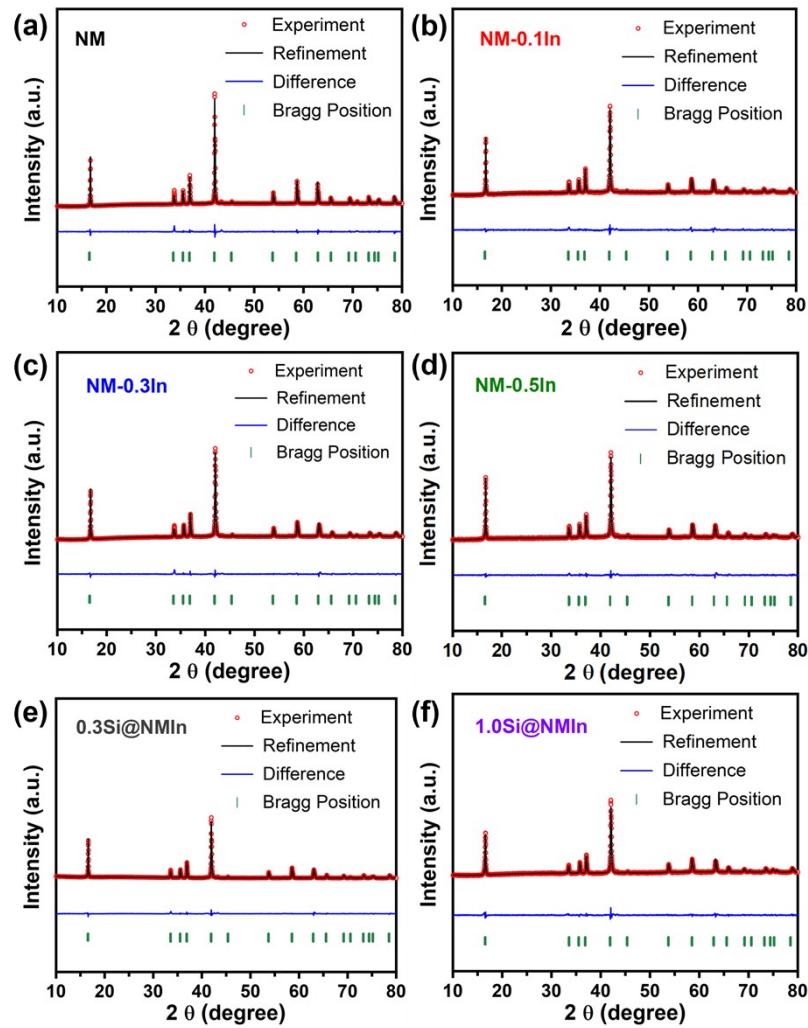
<sup>c</sup> School of Marine Science and Technology, Tianjin University, Tianjin, 300072, P. R. China.

Corresponding authors:

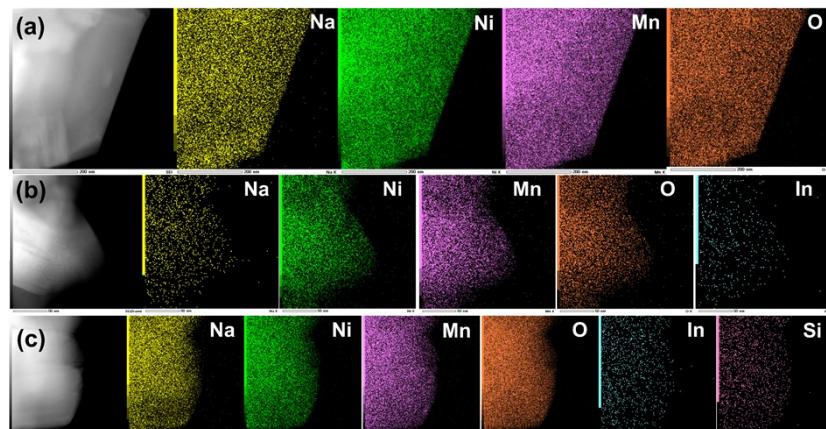
\* E-mail:

[liwei@tju.edu.cn](mailto:liwei@tju.edu.cn)

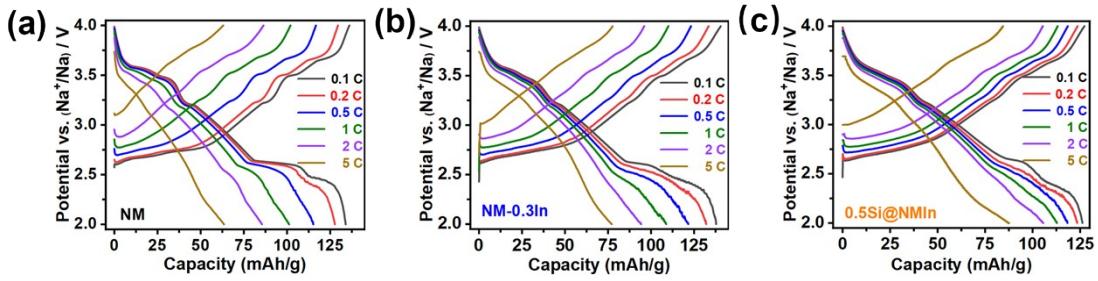
[wujiangjiexing2007@126.com](mailto:wujiangjiexing2007@126.com)



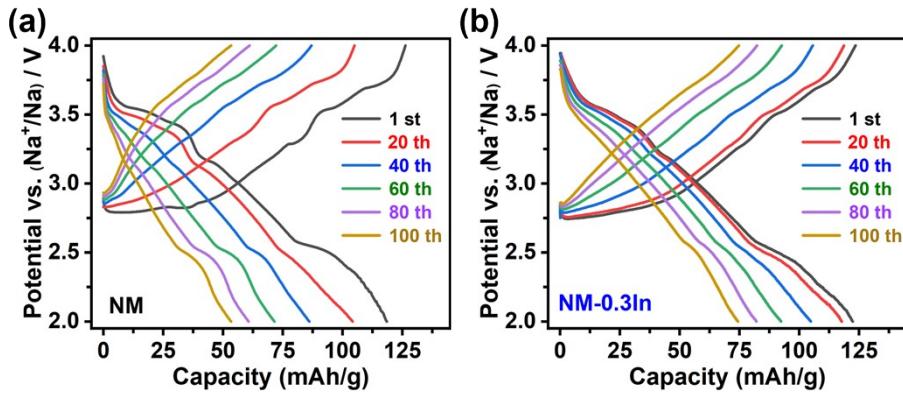
**Fig. S1** Rietveld refinement profiles of (a) NM, (b-d) modified with different In contents intercalation and (e, f) Si@In-doping samples.



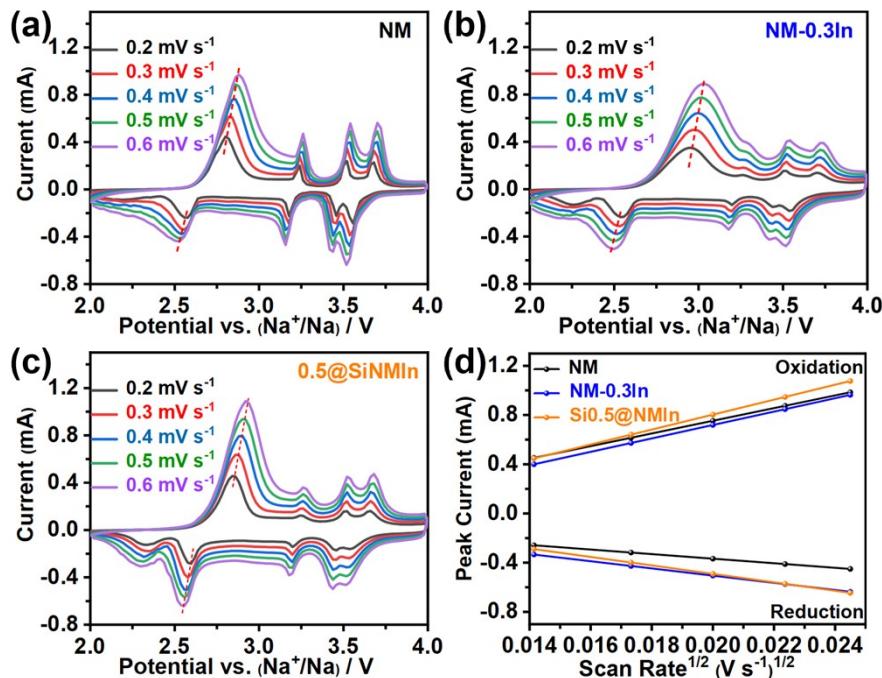
**Fig. S2** TEM elemental mappings of Na, O, Mn, Ni, In and Si of (a) NM, (b) NM-0.3In and (c) 0.5Si@NMIn



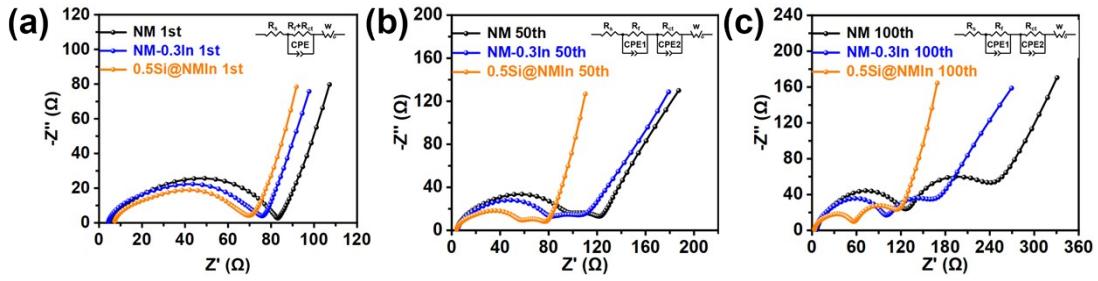
**Fig. S3** The charge-discharge curves of (a) the NM55, (b) the NM-0.3In and (c) the 0.5Si@NMIn at 2.0–4.0 V and 25 °C under different rates.



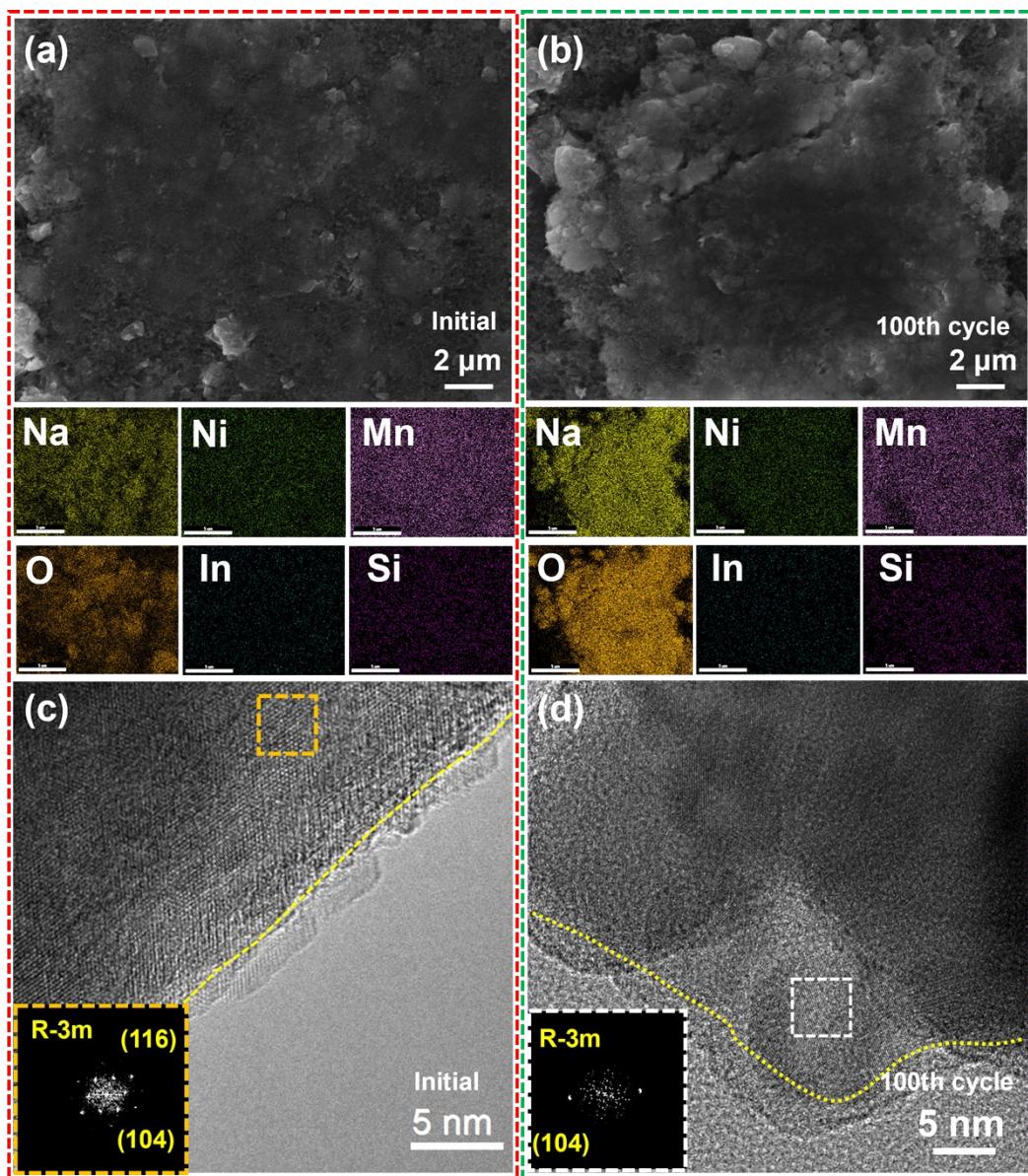
**Fig. S4** The galvanostatic charge-discharge (GCD) curves of (a) NM, (b) NM-0.3In.



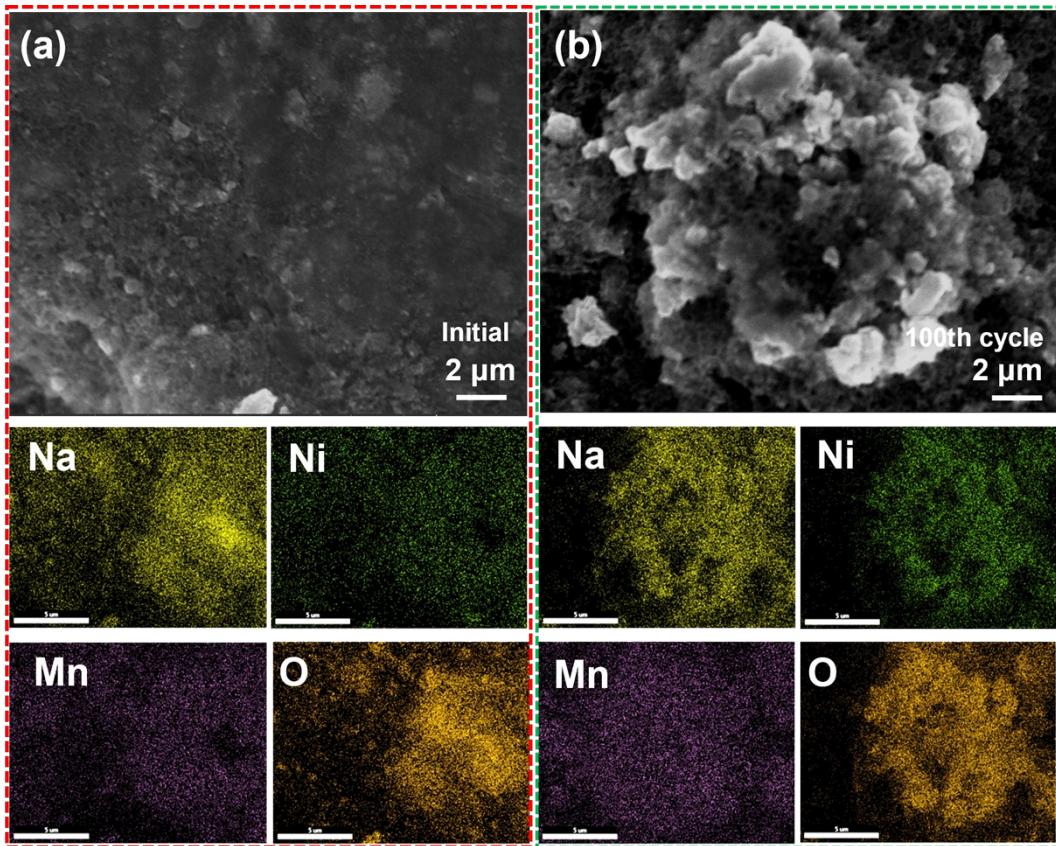
**Fig. S5** CV tests of (a) NM, (b) NM-0.3In and (c) 0.5Si@NMIn at the different scan rates. (d) The linear fitting of the peak currents of oxidation/reduction peaks at different scan rates with the square root of the scan rates.



**Fig. S6** The Nyquist plots of NM, NMIn-0.3 and 0.5Si@NMIn cathodes in the (a) 1st, (b) 50th and (c) 100th over 2.0-4.0 V.



**Fig. S7** SEM images of (a) the initial pole piece of 0.5Si@NMIn and (b) the spent pole piece of 0.5Si@NMIn experienced 100 cycles at 1 C. TEM images of (c) the fresh 0.5Si@NMIn and (d) the spent 0.5Si@NMIn experienced 100 cycles at 1 C.



**Fig. S8** SEM images of (a) the initial pole specie of NM and (b) the spent pole specie of NM experienced 100 cycles at 1 C.

**Table S1** Relative percentages and binding energies of  $\text{Ni}^{2+}/\text{Ni}^{3+}$  in Ni 2p XPS spectra.

Sample	Ni 2p <sub>3/2</sub> (eV)		Ni 2p <sub>1/2</sub> (eV)		Ni content (%)	
	Ni <sup>2+</sup>	Ni <sup>3+</sup>	Ni <sup>2+</sup>	Ni <sup>3+</sup>	Ni <sup>2+</sup>	Ni <sup>3+</sup>
NM	854.46	856.15	871.91	873.72	82.60	17.40
NM-0.3In	854.56	856.25	872.11	874.55	79.38	20.62
0.5Si@NMIn	854.79	856.58	872.42	874.65	75.65	24.35

**Table S2** Relative percentages and binding energies of  $\text{Mn}^{3+}/\text{Mn}^{4+}$  in Mn 2p XPS spectra.

Sample	Mn 2p <sub>3/2</sub> (eV)		Mn 2p <sub>1/2</sub> (eV)		Mn content (%)	
	Mn <sup>3+</sup>	Mn <sup>4+</sup>	Mn <sup>3+</sup>	Mn <sup>4+</sup>	Mn <sup>3+</sup>	Mn <sup>4+</sup>
NM	641.53	643.50	652.49	653.79	65.90	34.10
NM-0.3In	641.62	643.52	653.08	653.96	59.68	40.32
0.5Si@NMIn	641.85	643.66	653.03	654.01	57.37	42.63

**Table S3** Relative percentages and binding energies of oxygen species in O 1s XPS spectra.

Sample	Adsorbed O		O Vacancy		Lattice O	
	O 1s	O content	O 1s	O content	O 1s	O content
	(eV)	(%)	(eV)	(%)	(eV)	(%)
NM	528.75	11.18	530.93	77.98	535.27	10.84
NM-0.3In	528.81	9.95	530.98	79.16	535.31	10.89
0.5Si@NMIn	529.43	8.51	531.22	78.51	535.66	12.98

**Table S4** Na<sup>+</sup> diffusion coefficient ( $D_{\text{Na}^+}$ ) of NM, NM-0.3In and 0.5Si@NMIn.

Sample	$D_{\text{Na}^+}$ (cm <sup>2</sup> s <sup>-1</sup> )	
	Desodiation	Sodiation
NM	$3.48 \times 10^{-11}$	$4.55 \times 10^{-12}$
NM-0.3In	$3.65 \times 10^{-11}$	$8.90 \times 10^{-12}$
0.5Si@NMIn	$4.76 \times 10^{-11}$	$1.12 \times 10^{-11}$

**Table S5** EIS fitting results of NM, NM-0.3In and 0.5Si@NMIn.

Sample	Cycle	$R_s$ (Ω)	$R_f + R_{ct}$ (Ω)
NM	1 <sup>st</sup>	4.14	80.82
	50 <sup>th</sup>	2.93	128.45
	100 <sup>th</sup>	5.08	265.4
NM-0.3In	1 <sup>st</sup>	3.63	69.7
	50 <sup>th</sup>	3.42	118.38
	100 <sup>th</sup>	3.58	170.22
0.5Si@NMIn	1 <sup>st</sup>	6.15	63.78
	50 <sup>th</sup>	3.15	97.20
	100 <sup>th</sup>	1.86	124.87

**Table S6** Resistivity and conductivity results of NM, NM-0.3In and 0.5Si@NMIn.

Sample	Pressure (Mpa)	Resistivity (kΩ m)	Conductivity (S m <sup>-1</sup> )
NM	2	30.70	3.26×10 <sup>-5</sup>
	3	28.85	3.47×10 <sup>-5</sup>
	4	27.05	3.70×10 <sup>-5</sup>
NM-0.3In	2	27.91	3.58×10 <sup>-5</sup>
	3	26.02	3.84×10 <sup>-5</sup>
	4	24.11	4.15×10 <sup>-5</sup>
0.5Si@NMIn	2	22.98	4.35×10 <sup>-5</sup>
	3	20.87	4.79×10 <sup>-5</sup>
	4	18.91	5.29×10 <sup>-5</sup>

Galvanostatic intermittent titration technique (GITT) measurement in the 1<sup>st</sup> cycle and 100<sup>th</sup> cycle are utilized to determine the Na<sup>+</sup> diffusion coefficient ( $D_{\text{Na}^+}$ ) within NM, NM-0.3In and 0.5Si@NMIn cathodes. The  $D_{\text{Na}^+}$  value can be derived using the following formula:

$$D_{\text{Na}^+} = \frac{4}{\pi\tau} \left( \frac{m_B V_M}{M_B A} \right)^2 \left( \frac{\Delta E_S}{\Delta E_\tau} \right)^2 \quad (\text{S1})$$

Where  $\tau(\text{s})$  represents the galvanostatic current pulse time,  $V_M$ ,  $M_B$ , and  $m_B$  are the molar volume (obtained from the Rietveld refinement results from GSAS II), molecular weight, and the molar mass of the active material, respectively. Meanwhile,  $A$  signifies the electrode surface area,  $\Delta E_\tau$  and  $\Delta E_s$  is the voltage change during the constant current pulse and the corresponding relaxation process.